

## isc N-Channel MOSFET Transistor

## FDP4D5N10C

## • FEATURES

- With TO-220 packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## • APPLICATIONS

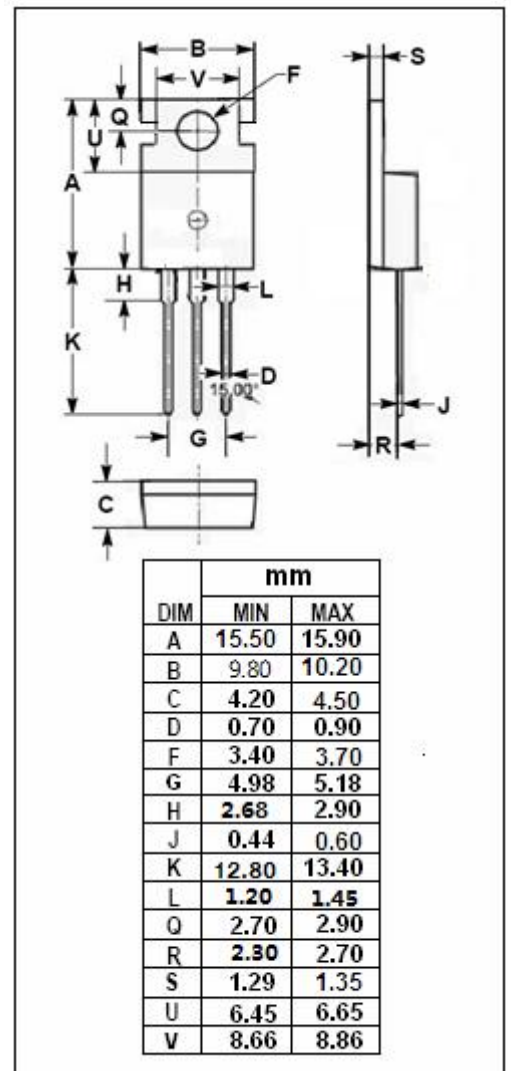
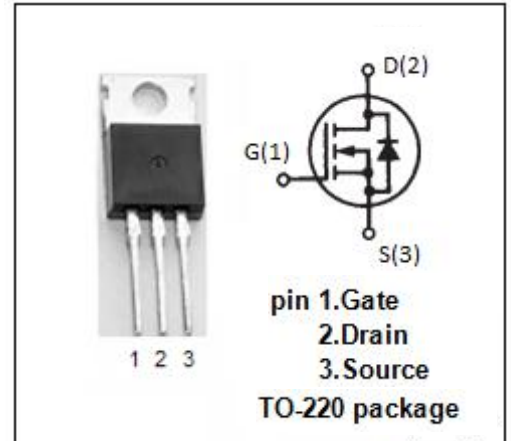
- Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS( $T_a=25^{\circ}\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DS}$	Drain-Source Voltage	100	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous;@ $T_c=25^{\circ}\text{C}$ $T_c=100^{\circ}\text{C}$	128 91	A
$I_{DM}$	Drain Current-Single Pulsed	512	A
$P_D$	Total Dissipation	37.5	W
$T_j$	Operating Junction Temperature	175	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature	-55~175	$^{\circ}\text{C}$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	4.0	$^{\circ}\text{C/W}$



**isc N-Channel MOSFET Transistor****FDP4D5N10C****ELECTRICAL CHARACTERISTICS****T<sub>c</sub>=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	100			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.31mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =100A			4.5	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 80V; V <sub>GS</sub> = 0V			1	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =100A, V <sub>GS</sub> = 0 V			1.3	V

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